

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/716,276	11/17/2003	Peter J. Hopper	P05731	6046	
7590 02/16/2005		EXAMINER			
Jurgen Vollrath			KANG, DONGHEE		
588 Sutter Street #531 San Francisco, CA 94102			ART UNIT	PAPER NUMBER	
			2811	2811	
		DATE MAILED: 02/16/2005			

Please find below and/or attached an Office communication concerning this application or proceeding.

	Amelia di an Na	A 1: 4/ -)				
	Application No.	Applicant(s)				
	10/716,276	HOPPER ET AL.				
Office Action Summary	Examiner	Art Unit				
	Donghee Kang	2811				
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a rep. If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailine earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be timely within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDONET	ely filed will be considered timely. the mailing date of this communication. (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 24 January 2005.						
2a) ☐ This action is FINAL . 2b) ☑ Thi						
3) Since this application is in condition for allowa	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
5) ☐ Claim(s) is/are allowed. 6) ☑ Claim(s) 8 and 9 is/are rejected. 7) ☑ Claim(s) 10-15 is/are objected to.	4a) Of the above claim(s) <u>1-7</u> is/are withdrawn from consideration. ☐ Claim(s) is/are allowed. ☐ Claim(s) <u>8 and 9</u> is/are rejected.					
Application Papers						
9) ☐ The specification is objected to by the Examin 10) ☑ The drawing(s) filed on 17 November 2003 is/ Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the E	are: a)⊠ accepted or b)□ object e drawing(s) be held in abeyance. See ction is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
Attachment(s)	. □	(PTO 442)				
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da					
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date	5) Notice of Informal P 6) Other:	atent Application (PTO-152)				

Application/Control Number: 10/716,276

Art Unit: 2811

DETAILED ACTION

Page 2

Election/Restrictions

1. Claims 1-7 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made without traverse in the reply filed on January 24, 2005.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claim 8 is rejected under 35 U.S.C. 102(b) as being anticipated by Anantha et al. (US 4,196,440).

Anantha et al. teach a method of forming a laterally extending trench in a semiconductor material underneath a base of a BJT, comprising (Figs. 2-6):

Choosing a predetermined crystal orientation, etching a vertically extending STI region region (Fig.2) next to the base, and using an anisotropic etchtant to etch the laterally extending trench (40) to extend laterally from the STI. See also Col.4, lines 4-48.

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and

the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Page 3

5. Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over Anantha et al. (US 4,196,440) in view of Kawakita et al. (US 4,685,198).

Anantha et al. do not explicitly teach choosing the crystal orientation includes choosing a wafer with <100> orientation. Kawakita et al. teach vertical opening are formed in the surface of {100} silicon substrate. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to choose crystal orientation <100> as taught by Kawakita et al. in Anantha's method in order to obtain vertical opening in the silicon substrate.

Allowable Subject Matter

6. Claims 10-15 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

Prior art reference, taken along or in combination, do not teach or render obvious that the choosing of the crystal orientation includes choosing a lateral trench direction that is in the <110> direction.

Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 571-272-1656. The examiner can normally be reached on Monday through Friday.

Art Unit: 2811

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Donghee Kang Primary Examiner Art Unit 2811

Knowposhee

dhk